

*Erik Jonsson School of Engineering and Computer Science*

***Realization of the First GaN Based Tunnel Field-Effect Transistor***

**UT Dallas Author(s):**

Qingxiao Wang  
Moon J. Kim

**Citation:**

Chaney, A., H. Turski, K. Nomoto, Q. Wang, et al. 2018. "Realization of the first GaN based tunnel field-effect transistor." Device Research Conference, 76th, doi: 10.1109/DRC.2018.8442249

Access to full text is restricted to users with a valid UT Dallas NetID and password. Authorized users may click the link below to gain entry into the publisher's website

<http://utd.edu/t/5232>